

PACKAGE/ORDERING INFORMATION

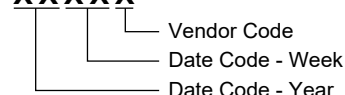
MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8044	SOIC-14	-40°C to +85°C	SGM8044YS14G/TR	SGM8044YS14 XXXXX	Tape and Reel, 2500
	TSSOP-14	-40°C to +85°C	SGM8044YTS14G/TR	SGM8044 YTS14 XXXXX	Tape and Reel, 3000
	TQFN-3×3-16L	-40°C to +85°C	SGM8044YTQ16G/TR	8044TQ XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.

SOIC-14/TSSOP-14/TQFN-3×3-16L

XXXXX



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

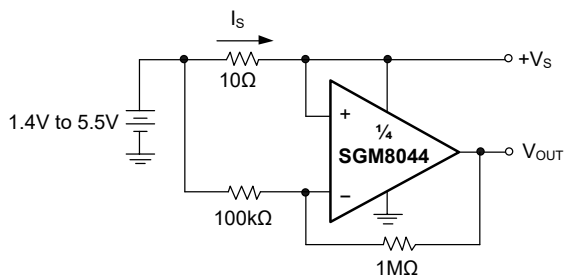
ABSOLUTE MAXIMUM RATINGS

Supply Voltage.....	6V
Analog Inputs (+IN, -IN).....	(-V _S) - 0.1V to (+V _S) + 0.1V
Differential Input Voltage.....	(-V _S) - (+V _S)
Junction Temperature.....	+150°C
Storage Temperature Range.....	-65°C to +150°C
Lead Temperature (Soldering, 10s).....	+260°C
ESD Susceptibility	
HBM.....	4000V
MM.....	400V

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range.....	1.4V to 5.5V
Operating Temperature Range.....	-40°C to +85°C

TYPICAL APPLICATION



$$I_s = \frac{+V_S - V_{OUT}}{(10V/V) \cdot (10\Omega)}$$

High-side Battery Current Sensor

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

ELECTRICAL CHARACTERISTICS

(At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V}$ to 5V , $-V_S = \text{GND}$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$ ⁽¹⁾, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DC Electrical Characteristics						
Input Offset Voltage	V_{OS}	$V_{CM} = +V_S/2$		0.7	2.5	mV
Input Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$V_{CM} = +V_S/2$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		2.5		$\mu\text{V}/^\circ\text{C}$
Power Supply Rejection Ratio	PSRR	$+V_S = 1.4\text{V}$ to 5.5V	74	80		dB
Input Common Mode Voltage Range	V_{CMR}		$(-V_S) - 0.1$		$(+V_S) + 0.1$	V
Common Mode Rejection Ratio	CMRR	$+V_S = 5.0\text{V}$, $V_{CM} = -0.1\text{V}$ to 5.1V	65	83		dB
		$+V_S = 5.0\text{V}$, $V_{CM} = 2.5\text{V}$ to 5.1V	65	82		
		$+V_S = 5.0\text{V}$, $V_{CM} = -0.1\text{V}$ to 2.5V	70	80		
Large-Signal Voltage Gain	A_{VO}	$+V_S = 1.4\text{V}$, $R_L = 50\text{k}\Omega$, $V_{OUT} = (+V_S) - 0.1\text{V}$	72	77		dB
		$+V_S = 2.5\text{V}$, $R_L = 50\text{k}\Omega$, $V_{OUT} = (+V_S) - 0.1\text{V}$		87		
		$+V_S = 5.0\text{V}$, $R_L = 50\text{k}\Omega$, $V_{OUT} = (+V_S) - 0.1\text{V}$	82	93		
Input Bias Current	I_B			1		pA
Input Offset Current	I_{OS}			1		pA
Maximum Output Voltage Swing	V_{OH}	$+V_S = 1.4\text{V}$, $R_L = 50\text{k}\Omega$	1.390	1.394		V
		$+V_S = 2.5\text{V}$, $R_L = 50\text{k}\Omega$		2.497		
		$+V_S = 5.0\text{V}$, $R_L = 50\text{k}\Omega$	4.990	4.996		
	V_{OL}	$+V_S = 1.4\text{V}$, $R_L = 50\text{k}\Omega$		5.4	10	mV
		$+V_S = 2.5\text{V}$, $R_L = 50\text{k}\Omega$		3.4		
		$+V_S = 5.0\text{V}$, $R_L = 50\text{k}\Omega$		3.7	10	
Output Short-Circuit Current	I_{SC}	$+V_S = 2.5\text{V}$		5.2		mA
		$+V_S = 5.0\text{V}$	22	23		
Supply Voltage	V_{CC}		1.4		5.5	V
Quiescent Current/Amplifier	I_Q	$+V_S = 1.4\text{V}$		550		nA
		$+V_S = 2.5\text{V}$		610		
		$+V_S = 5.0\text{V}$		670	1500	

ELECTRICAL CHARACTERISTICS (continued)

(At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V}$ to 5V , $-V_S = \text{GND}$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$, $C_L = 60\text{pF}$ ⁽¹⁾, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
AC Electrical Characteristics						
Gain-Bandwidth Product	GBP	$+V_S = 1.4\text{V}$		13.5		kHz
		$+V_S = 2.5\text{V}$		14.5		
		$+V_S = 5.0\text{V}$		15		
Slew Rate	SR	$+V_S = 1.4\text{V}$, $V_{OUT} = 1\text{V}$ Step		3.0		V/ms
		$+V_S = 2.5\text{V}$, $V_{OUT} = 1\text{V}$ Step		3.1		
		$+V_S = 5.0\text{V}$, $V_{OUT} = 2\text{V}$ Step		3.4		
Phase Margin	PM	$+V_S = 1.4\text{V}$ to 5.5V		60		°
Input Voltage Noise	$e_{n\text{P-P}}$	$+V_S = 1.4\text{V}$, $f = 0.1\text{Hz}$ to 10Hz		3.5		$\mu\text{V}_{\text{P-P}}$
		$+V_S = 2.5\text{V}$, $f = 0.1\text{Hz}$ to 10Hz		3.4		
		$+V_S = 5.0\text{V}$, $f = 0.1\text{Hz}$ to 10Hz		3.2		
Input Voltage Noise Density	e_n	$+V_S = 1.4\text{V}$, $f = 1\text{kHz}$		205		$\text{nV}/\sqrt{\text{Hz}}$
		$+V_S = 2.5\text{V}$, $f = 1\text{kHz}$		185		
		$+V_S = 5.0\text{V}$, $f = 1\text{kHz}$		190		

NOTE: 1. Refer to Figure 1 and Figure 2.

TEST CIRCUITS

The test circuits used for the DC and AC tests are shown in Figure 1 and Figure 2.

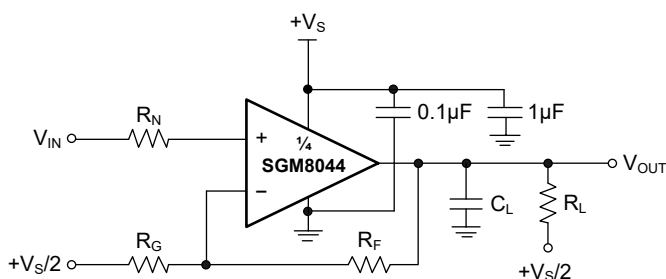


Figure 1. AC and DC Test Circuit for Most Non-Inverting Gain Configurations

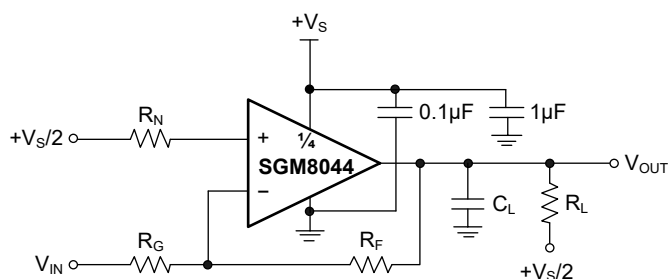
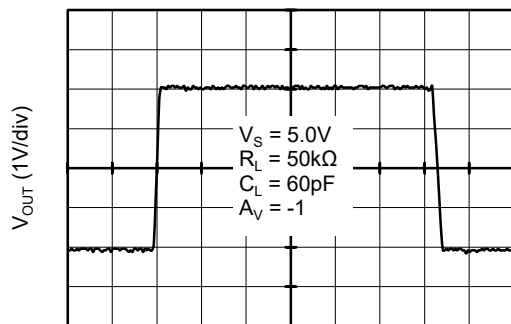


Figure 2. AC and DC Test Circuit for Most Inverting Gain Configurations

TYPICAL PERFORMANCE CHARACTERISTICS

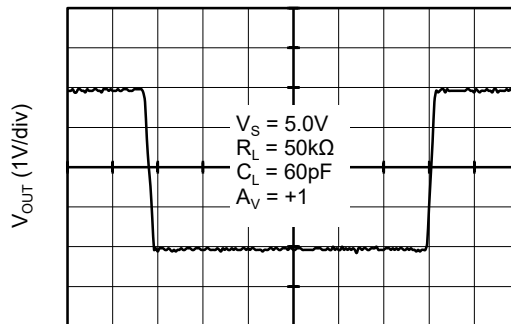
At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V to } 5\text{V}$, $-V_S = \text{GND}$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$, $C_L = 60\text{pF}$, unless otherwise noted.

Large-Signal Inverting Pulse Response



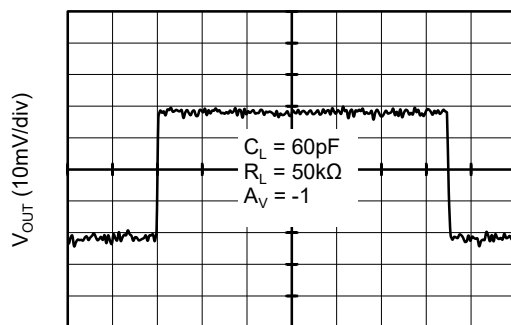
Time (5ms/div)

Large-Signal Non-Inverting Pulse Response



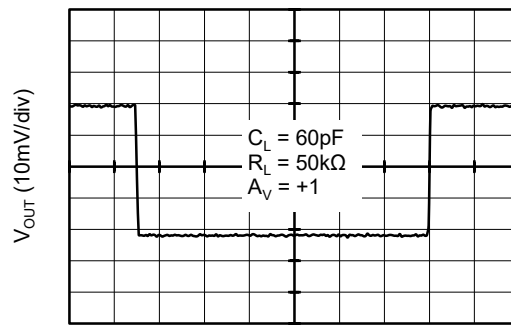
Time (5ms/div)

Small-Signal Inverting Pulse Response



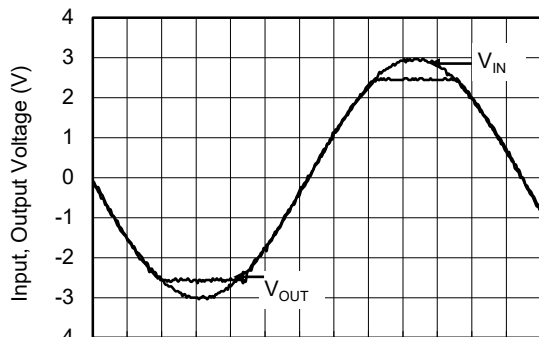
Time (5ms/div)

Small-Signal Non-Inverting Pulse Response



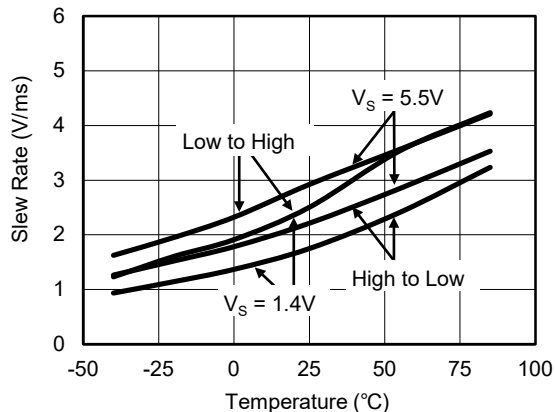
Time (5ms/div)

No Phase Reversal



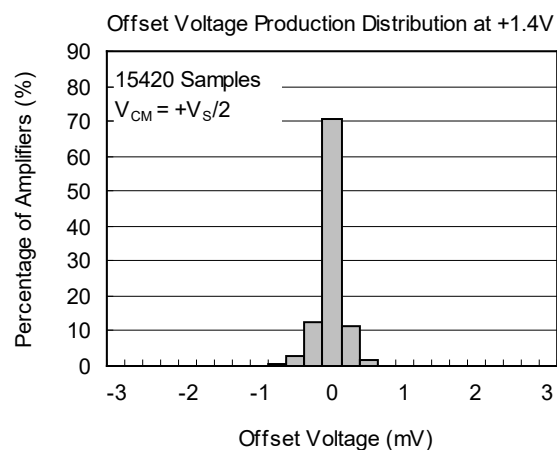
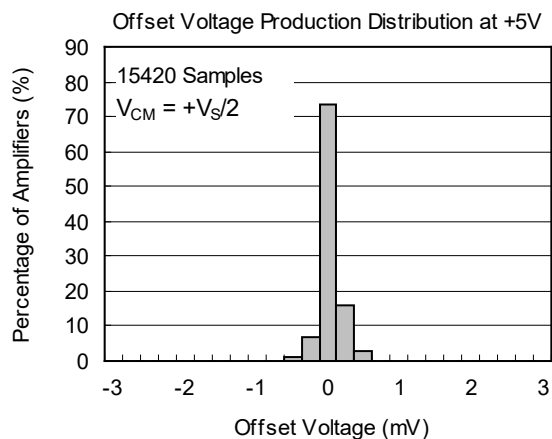
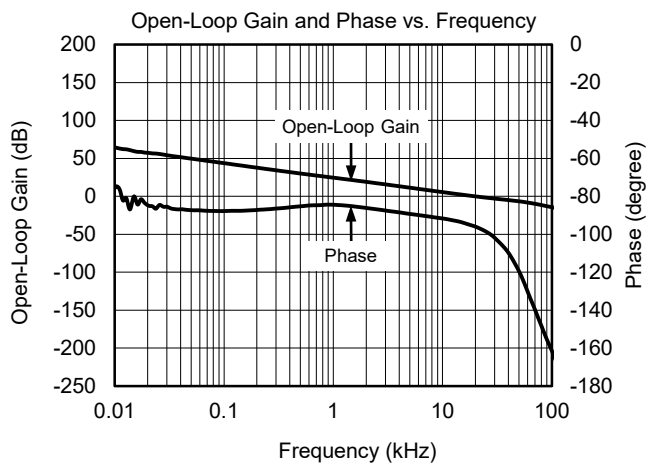
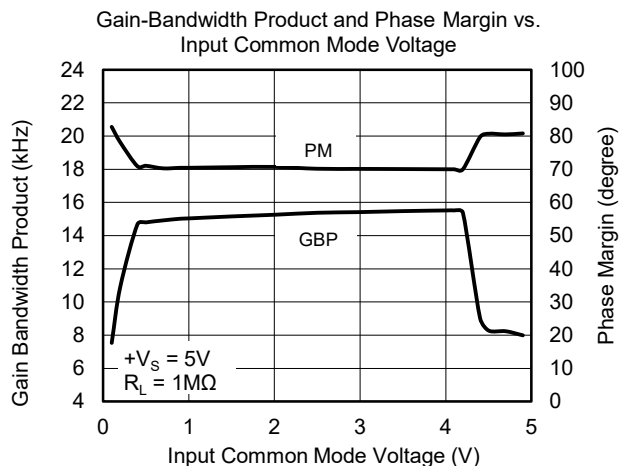
Time (5ms/div)

Slew Rate vs. Temperature



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $+V_S = 1.4\text{V to } 5\text{V}$, $-V_S = \text{GND}$, $V_{CM} = +V_S/2$, $V_{OUT} \approx +V_S/2$ and $R_L = 1\text{M}\Omega$ to $+V_S/2$, $C_L = 60\text{pF}$, unless otherwise noted.



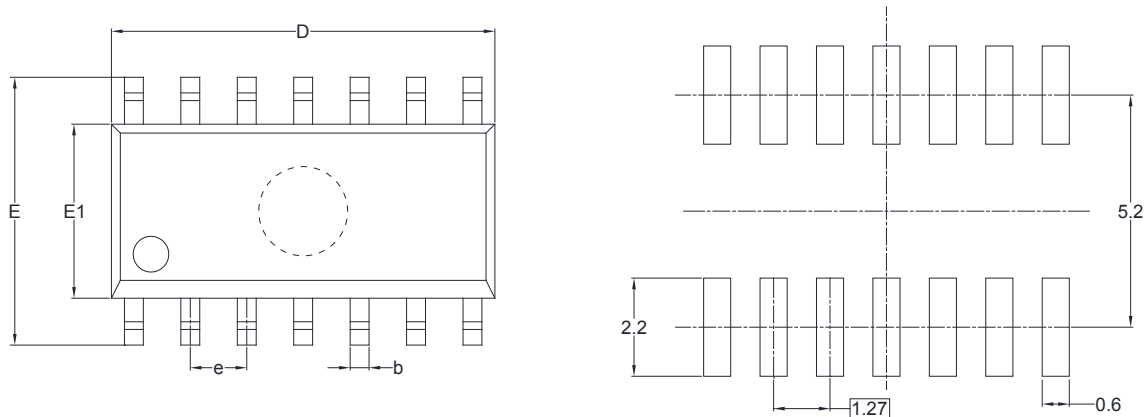
REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

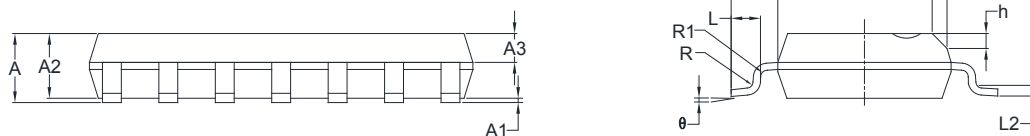
OCTOBER 2017 – REV.A.3 to REV.A.4	Page
Updated Typical Performance Characteristics section	6
SEPTEMBER 2015 – REV.A.2 to REV.A.3	Page
Added TQFN-3×3-16L Package	All
Updated Package Outline Dimensions section	7~8
JANUARY 2013 – REV.A.1 to REV.A.2	Page
Added Tape and Reel Information section	9~10
MAY 2011 – REV.A to REV.A.1	Page
Updated Package Description	All
Changes from Original (JUNE 2010) to REV.A	Page
Changed from product preview to production data.....	All

PACKAGE OUTLINE DIMENSIONS

SOIC-14



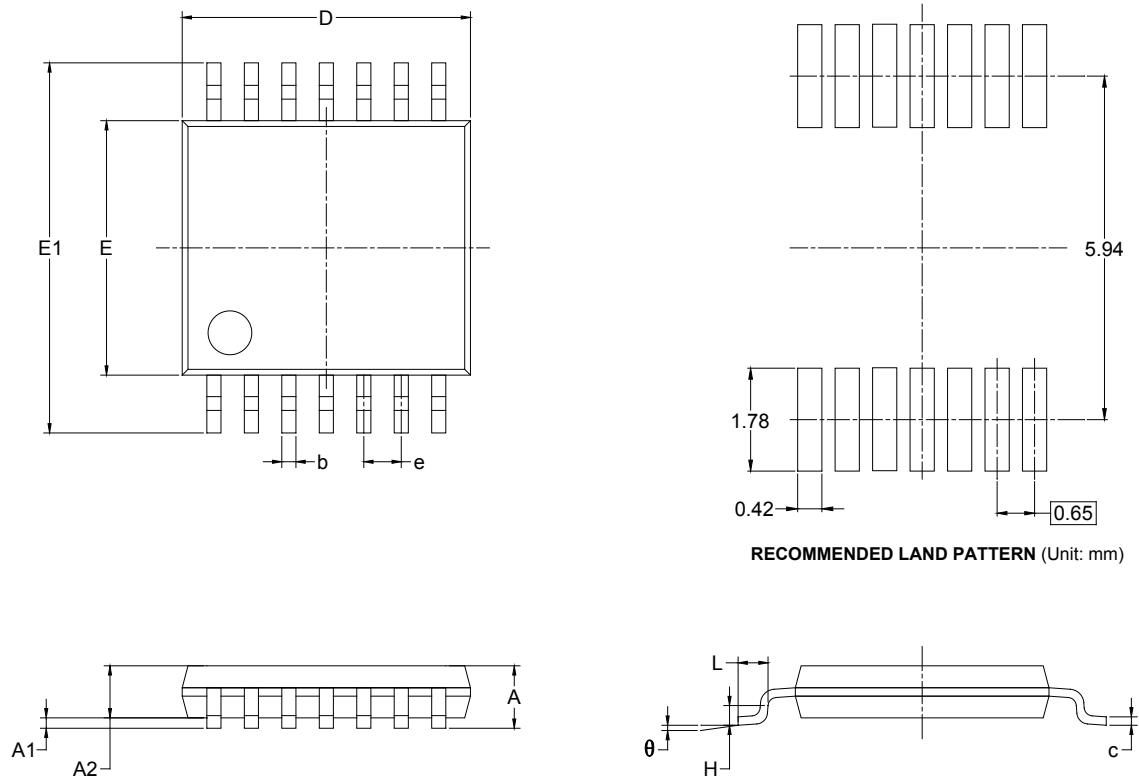
RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.053	0.069
A1	0.10	0.25	0.004	0.010
A2	1.25	1.65	0.049	0.065
A3	0.55	0.75	0.022	0.030
b	0.36	0.49	0.014	0.019
D	8.53	8.73	0.336	0.344
E	5.80	6.20	0.228	0.244
E1	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
L	0.45	0.80	0.018	0.032
L1	1.04 REF		0.040 REF	
L2	0.25 BSC		0.01 BSC	
R	0.07		0.003	
R1	0.07		0.003	
h	0.30	0.50	0.012	0.020
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

TSSOP-14

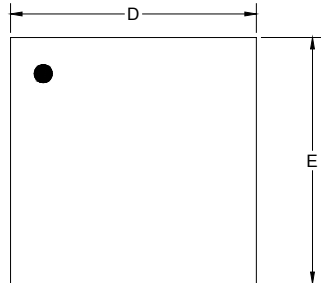


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650 BSC		0.026 BSC	
L	0.500	0.700	0.02	0.028
H	0.25 TYP		0.01 TYP	
θ	1°	7°	1°	7°

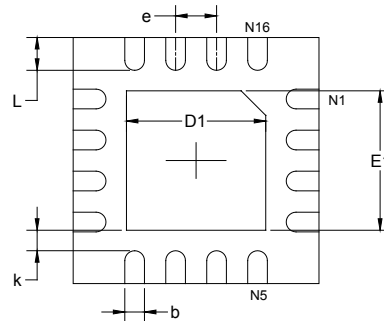
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

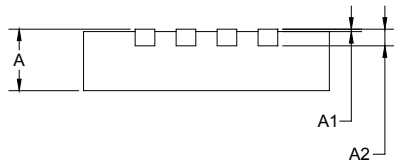
TQFN-3×3-16L



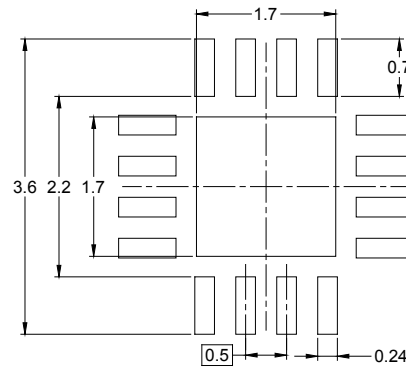
TOP VIEW



BOTTOM VIEW



SIDE VIEW



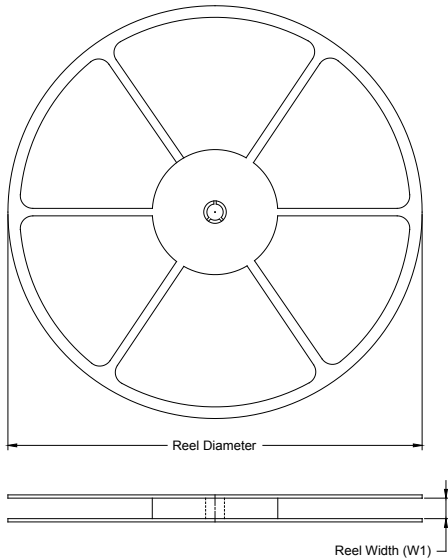
RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203 REF		0.008 REF	
D	2.900	3.100	0.114	0.122
D1	1.600	1.800	0.063	0.071
E	2.900	3.100	0.114	0.122
E1	1.600	1.800	0.063	0.071
k	0.200 MIN		0.008 MIN	
b	0.180	0.300	0.007	0.012
e	0.500 TYP		0.020 TYP	
L	0.300	0.500	0.012	0.020

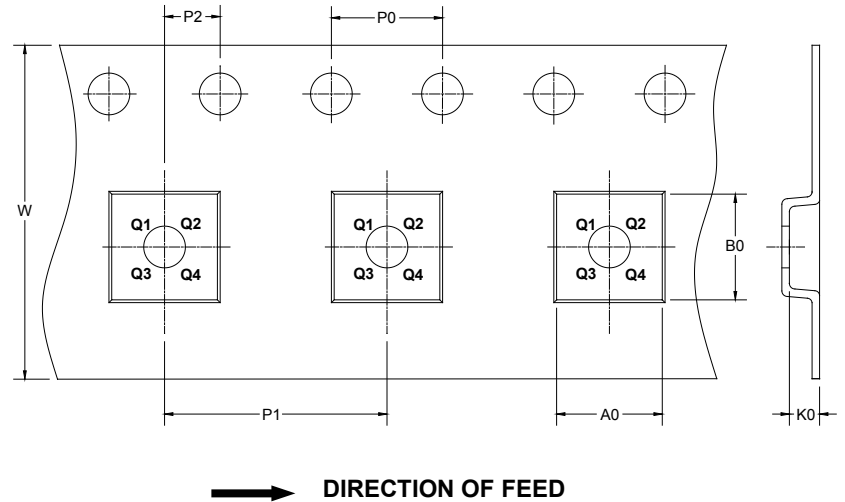
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-14	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP-14	13"	12.4	6.95	5.60	1.20	4.0	8.0	2.0	12.0	Q1
TQFN-3×3-16L	13"	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1

DD0001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5

DD0002